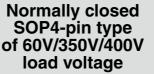
Panasonic



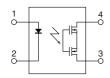




PhotoMOS® GU SOP 1 Form B (AQY41OS)

4.3 .169 .173 12.1 .083

mm inch



RoHS compliant

FEATURES

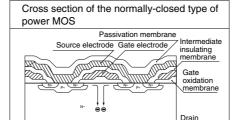
1. Small SOP4-pin package

The device comes in a super-miniature SO package 4-pin type measuring (W) 4.3×(L) 4.4×(H) 2.1 mm (W) .169×(L) .173×(H) .083 inch

2. Low on-resistance

The AQO4 series (normally closed type) has a low on-resistance.

This has been achieved thanks to the built-in MOSFET processed by our proprietary method, DSD (Double-diffused and Selective Doping) method.



3. Controls low-level analog signals

PhotoMOS feature extremely low closedcircuit offset voltage to enable control of low-level analog signals without distortion.

4. Low-level off-state leakage current of max. 1 μA

TYPICAL APPLICATIONS

- Power supply
- Measuring instruments
- Security equipment
- Telephone equipment
- Sensing equipment

TYPES

	Output rating*			Part No.			Packing quantity	
	Lood	Load Load oltage current	Package	Tube packing style	Tape and reel packing style			
	voltage				Picked from the 1/2-pin side	Picked from the 3/4-pin side	Tube	Tape and reel
	60V	500mA		AQY412S	AQY412SX	AQY412SZ	1 tube contains:	
AC/DC dual use	350V	120mA	SOP4-pin	AQY410S	AQY410SX	AQY410SZ	100 pcs. 1 batch contains:	1,000 pcs.
	400V	100mA		AQY414S	AQY414SX	AQY414SZ	2,000 pcs.	1

^{*} Indicate the peak AC and DC values.

Note: For space reasons, the three initial letters of the part number "AQY", the surface mount terminal shape indicator "S" and the packing style indicator "X" or "Z" are not marked on the device. (Ex. the label for product number AQY412SX is 412)

RATING

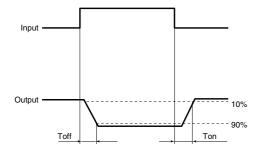
1. Absolute maximum ratings (Ambient temperature: 25°C 77°F)

Item		Symbol	AQY412S	AQY410S	AQY414S	Remarks
Input	LED forward current	lF	50 mA			
	LED reverse voltage	VR	5 V			
	Peak forward current	IFP	1 A			f = 100 Hz, Duty factor = 0.1%
	Power dissipation	Pin	75 mW			
	Load voltage (peak AC)	VL	60 V	350 V	400 V	
Output	Continuous load current	l _L	0.5 A	0.12 A	0.1 A	Peak AC, DC
Output	Peak load current	Ipeak	1.5 A	0.3 A	0.24 A	100ms (1 shot), V _L = DC
	Power dissipation	Pout	300 mW			
Total power dissipation		Рт	350 mW			
I/O isolation voltage		Viso	1,500 V AC			
Temperture limits	Operating	Topr	-40°C to +85°C -40°F to +185°F			Non-condensing at low temperatures
	Storage	Tstg	-40°C to +100°C -40°F to +212°F			

2. Electrical characteristics (Ambient temperature: 25°C 77°F)

	Item	Symbol	AQY412S	AQY410S	AQY414S	Remarks	
	LED operate (OFF) current	Typical	Foff	0.9 mA			IL = Max.
	LED operate (OFF) current	Maximum					
Input	LED reverse (ON) current	Minimum	Fon	0.4 mA			I∟ = Max.
Input	LED reverse (ON) current	Typical					
	LED dropout voltage	Typical	VF	1.25 V (1.14 V at I _F = 5 mA)			I _F = 50 mA
	LED diopodi voltage	Maximum	VF	1.5 V			
	0	Typical	Ron	1 Ω	18 Ω	26 Ω	IF = 0 mA
Output	On resistance	Maximum	H on	2.5 Ω	25 Ω	35 Ω	I∟ = Max. Within 1 s on time
•	Off state leakage current	Maximum	ILeak	1 μΑ			I _F = 5 mA V _L = Max.
	Onerete (OFF) time*	Typical	Toff	0.9 ms	0.52 ms	0.47 ms	I _F = 0 mA → 5 mA I _L = Max.
	Operate (OFF) time*	Maximum	loff	3 ms	11	ms	
	Reverse (ON) time*	Typical	- Ton	0.21 ms	0.23 ms	0.28 ms	$I_F = 5 \text{ mA} \rightarrow 0 \text{ mA}$
Transfer characteristics	heverse (ON) time	Maximum	Ion	1 ms			I∟ = Max.
Characteristics	I/O conscitones	Typical	Ciso	0.8 pF			f = 1 MHz
	I/O capacitance	Maximum	Ciso	1.5 pF			V _B = 0 V
	Initial I/O isolation resistance Minimum		Riso	1,000 ΜΩ			500 V DC

^{*}Operate/Reverse time



RECOMMENDED OPERATING CONDITIONS

Please obey the following conditions to ensure proper device operation and resetting.

<u> </u>	•		•
Item	Symbol	Recommended value	Unit
Input LED current	lF	5	mA

■ These products are not designed for automotive use.

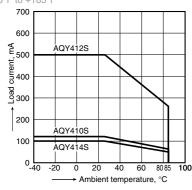
If you are considering to use these products for automotive applications, please contact your local Panasonic Corporation technical representative.

REFERENCE DATA

1. Load current vs. ambient temperature characteristics

Allowable ambient temperature: -40°C to +85°C

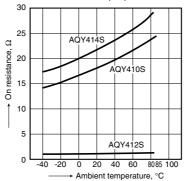
-40°F to +185°F



2. On resistance vs. ambient temperature characteristics

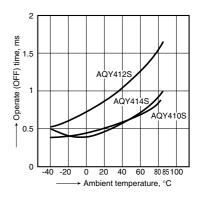
Measured portion: between terminals 3 and 4; LED current: 0 mA; $\label{eq:mass} % \begin{subarray}{ll} \end{subarray} % \begin{subarray}{ll} \e$

Continuous load current: Max.(DC)



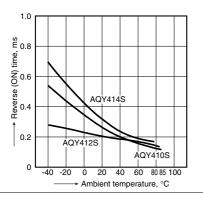
3. Operate (OFF) time vs. ambient temperature characteristics

LED current: 5 mA; Load voltage: Max.(DC); Continuous load current: Max.(DC)



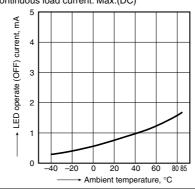
4. Reverse (ON) time vs. ambient temperature characteristics

LED current: 5 mA; Load voltage: Max.(DC); Continuous load current: Max.(DC)



5. LED operate (OFF) current vs. ambient temperature characteristics

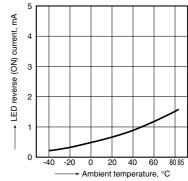
Sample: All types; Load voltage: Max.(DC); Continuous load current: Max.(DC)



6. LED reverse (ON) current vs. ambient temperature characteristics Sample: All types;

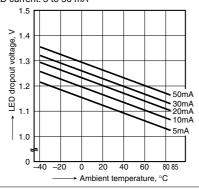
Load voltage: Max.(DC);

Continuous load current: Max.(DC)



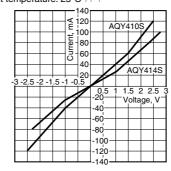
7. LED dropout voltage vs. ambient temperature characteristics Sample: All types;

LED current: 5 to 50 mA



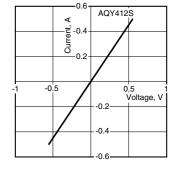
8-(1). Current vs. voltage characteristics of output at MOS portion

Measured portion: between terminals 3 and 4; Ambient temperature: 25°C 77°F



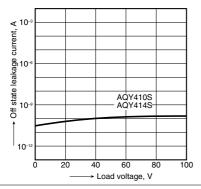
8-(2). Current vs. voltage characteristics of output at MOS portion

Measured portion: between terminals 3 and 4; Ambient temperature: 25°C 77°F



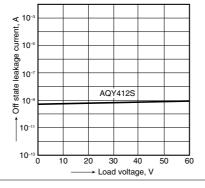
9-(1). Off state leakage current vs. load voltage characteristics

Measured portion: between terminals 3 and 4; LED current: 5 mA; Ambient temperature: 25°C 77°F



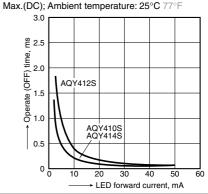
9-(2). Off state leakage current vs. load voltage characteristics

Measured portion: between terminals 3 and 4; LED current: 5 mA; Ambient temperature: 25°C 77°F



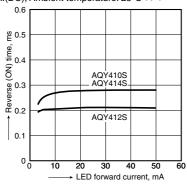
10. Operate (OFF) time vs. LED forward current characteristics

Measured portion: between terminals 3 and 4; Load voltage: Max.(DC); Continuous load current:



11. Reverse (ON) time vs. LED forward current characteristics

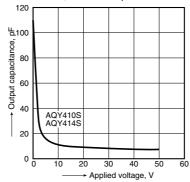
Measured portion: between terminals 3 and 4; Load voltage: Max.(DC); Continuous load current: Max.(DC); Ambient temperature: 25°C 77° F



12-(1). Output capacitance vs. applied voltage characteristics

Measured portion: between terminals 3 and 4; Frequency: 1 MHz;

LED current: 5 mA; Ambient temperature: 25°C 77°F



12-(2). Output capacitance vs. applied voltage characteristics

Measured portion: between terminals 3 and 4; Frequency: 1 MHz;

LED current: 5 mA; Ambient temperature: 25°C 77°F

